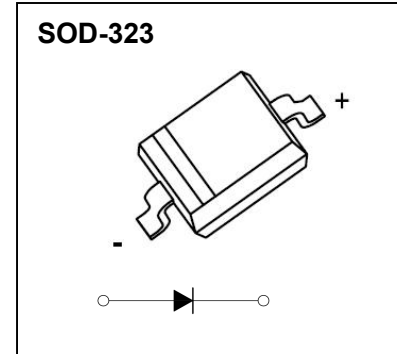
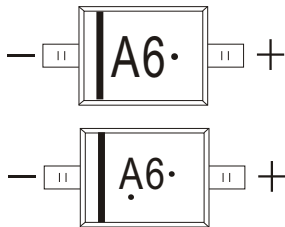


SWITCHING DIODE
FEATURES

- Very Small Plastic Package
- High Switching Speed

APPLICATIONS

- High-Speed Switching in e.g. Surface Mounted Circuits

MARKING: A6


The marking bar indicates the cathode
Solid dot = Green molding compound device,
if none, the normal device.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

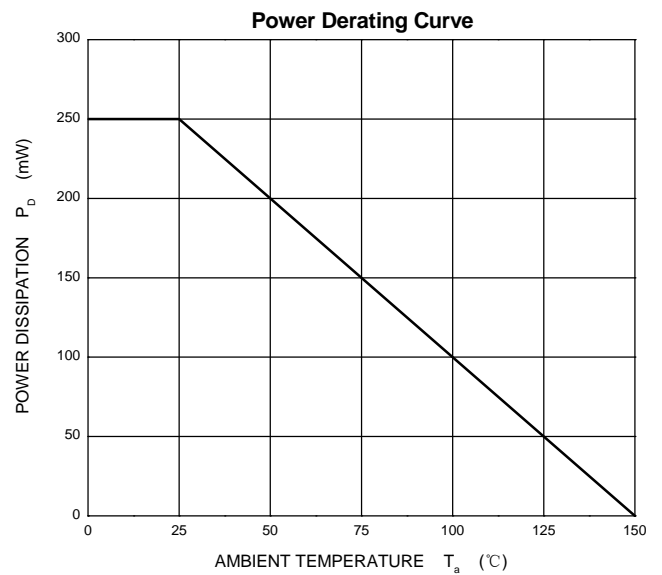
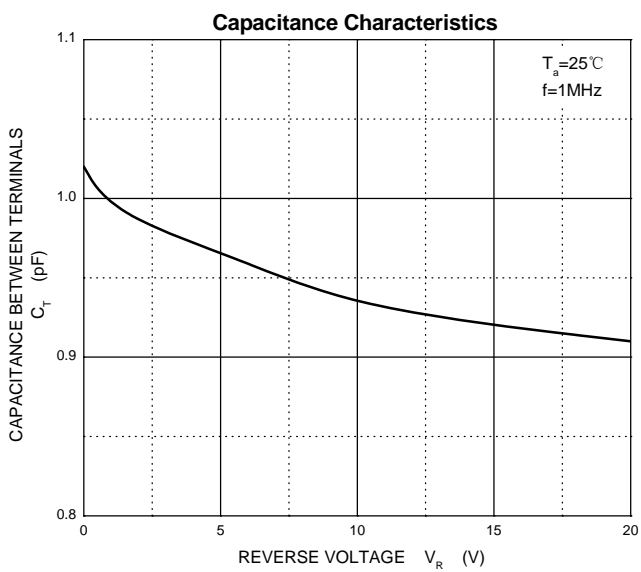
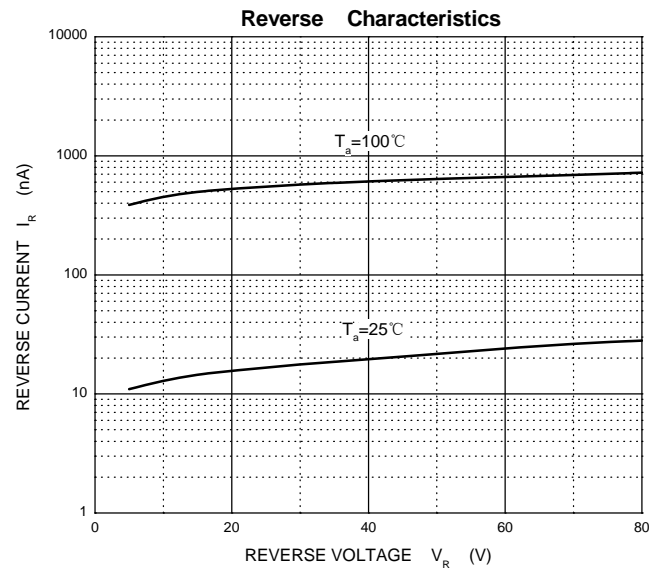
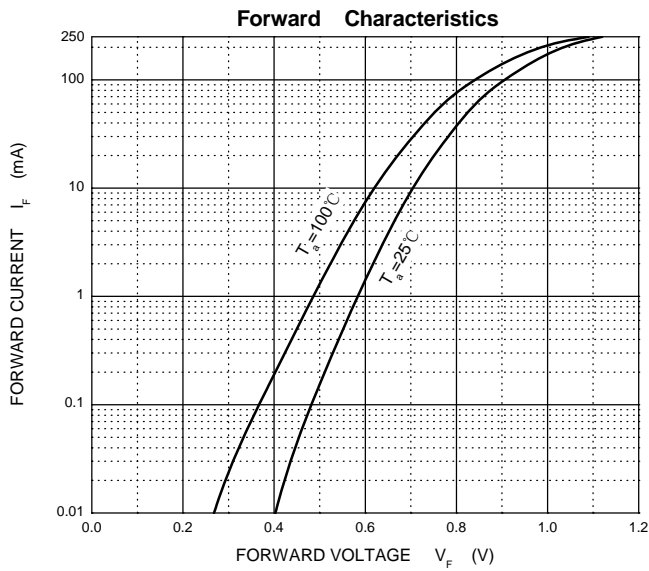
Symbol	Parameter	Value	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	85	V
V_R	DC Blocking Voltage	75	
I_o	Continuous Forward Current	250	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current@ $t=8.3\text{ms}$	2.0	A
P_D	Power Dissipation	250	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	500	$^\circ\text{C/W}$
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

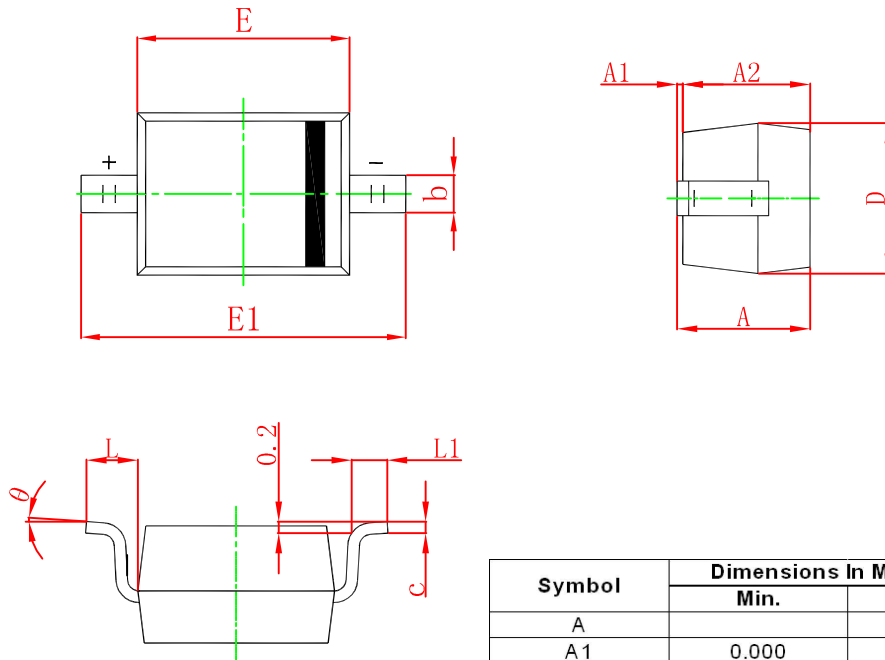
ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	100			V
Reverse current	I_R	$V_R=25\text{V}$			30	nA
		$V_R=75\text{V}$			1	μA
Forward voltage	V_F	$I_F=1\text{mA}$			0.715	V
		$I_F=10\text{mA}$			0.855	
		$I_F=50\text{mA}$			1	
		$I_F=150\text{mA}$			1.25	
Total capacitance	C_{tot}	$V_R=0\text{V}, f=1\text{MHz}$			1.5	pF
Reverse recovery time	t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=0.1 \times I_R$			4	ns

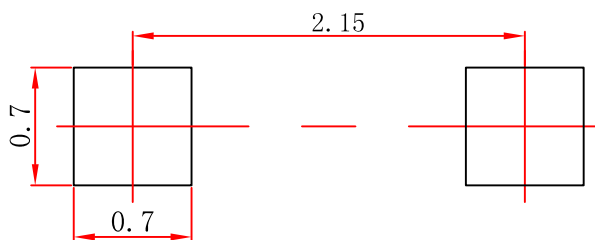


Typical Characteristics



SOD-323 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A		1.000		0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°		8°	

SOD-323 Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.